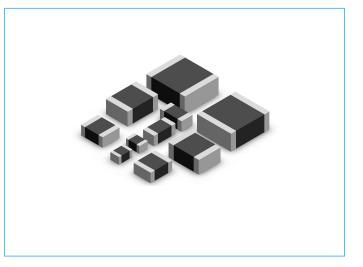




SV0806H271G0F

Description

The SV0806H271G0F is based on Multilayer fabrication technology. These components are designed to suppress a variety of transient events, including those specified in IEC 61000-4-2 or other standards used for Electromagnetic Compliance (EMC). The SV0806H271G0F is typically applied to protect integrated circuits and other components at the circuit board level. It can operate over a wider temperature range than zener diodes.



Features

- Rectangle, sizes serialization for hybrid integrated circuit or printed circuit surface mount components
- There are many side electrode lead-out material, particularly suitable for surface mount technology for solderability and resistance to soldering heat of the stringent requirements
- ♦ Fast response (<1ns)</p>
- Low leakage current, low clamping voltage
- Suitable for reflow, wave soldering and hot air hand soldering

Applications

- Application for Mother Board, Notebook, Cellular Phone, PDA, handheld device, DSC, DV, Scanner, and Set- Top Box...etc.
- Suitable for Push-Button, Power Line and Low Frequency single line over-voltage protect.





SV0806H271G0F

Electrical Characteristics (25±5°C)

Symbol	Minimum	Typical	Maximum	Units
V _{RMS}	—	_	175	V
VDC	—	—	225	V
Vv	243	_	297	V
Vc	_	_	450	V
I _{max}	_	_	150	A

 V_{RMS} - Maximum AC operating voltage the varistor can maintain and not exceed 10µA leakage current.

 V_{DC} - Maximum DC operating voltage the varistor can maintain and not exceed 10µA leakage current.

- $V_V\,$ Voltage across the device measure at 1mA DC current. Equivalent to V_{BR} "breakdown voltage".
- Vc Maximum peak current across the varistor with 8/20µs waveform and 1A pulse current.
- I_{max} Maximum peak current which may be applied with 8/20µs waveform without device failure.





SV0806H271G0F

Shape & Dimensions and Parts & Components

Shape & Dimensions: See Fig.1 and Table 1. Parts &Components: See Fig.2 and Table 2.

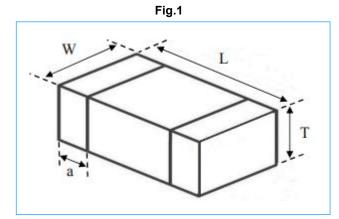


Table 1					
Туре	L (mm)	W (mm)	T (mm)	a (mm)	
0806	2.3+0.2/-0.2	1.8+0.2/-0.2	2.0 Max.	0.50±0.30	

Fig.2

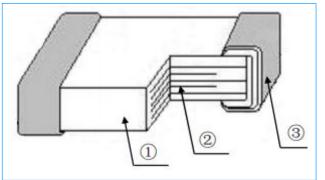


Table 2						
Part	1	2	3			
Component	ZnO Semiconductor Ceramics for Chip Varistor	Internal Electrode (Ag or Ag-Pd)	Terminal Electrode (Ag/Ni/Sn three layers)			

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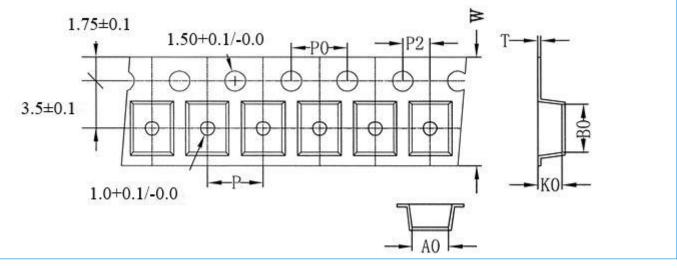




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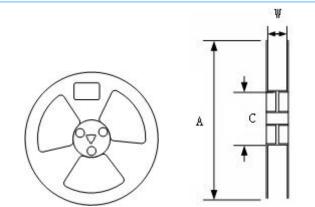
Taping

Carrier Tape Dimensions (Unit: mm)



Туре	A0	B0	K0	T	W	P0	P	P2
	(±0.2)	(±0.2)	Max.	Max.	(±0.3)	(土0.2)	(土0.2)	(±0.2)
0806	2.1	2.5	2.5	0.3	8.0	4.0	4.0	2.0

Taping Reel Dimensions (Unit: mm)



Turne	D irector	Dimensions			
Туре	Spec.	А	W	С	
0806	7"	178±2	8.4+2.0/-0.0	58±2	

Packaging Quantity

Туре	Таре	Quantity (pcs/reel)
0806	Embossed Tape	2000

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		@SOCAY Electronics Corp., Ltd. 2021
Revision January 15, 2021	4/5	Specifications are subject to change without notice.

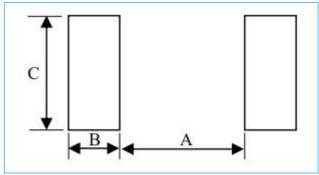




SV0806H271G0F

Soldering Recommendation

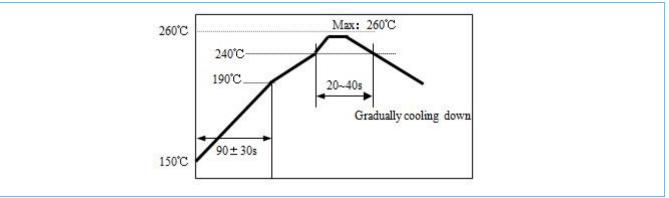
Recommended Land Pattern



Туре	A (mm)	B (mm)	C (mm)
0806	1.4~1.8	0.8~1.2	1.8~2.2

Recommended Soldering Profile

- Pb Free Solder Paste: Sn/Ag/Cu (96.5/3.0/0.5).
- Max time at max temp: 10sec.
- Allowed Reflow time: 2x Max.



Notes & Warnings

- ◆ Storage temperature in original packaging: -10~+40 °C.
- ♦ Relative Humidity: ≤70%RH.
- Keep away from corrosive atmosphere and sunlight.
- Period of Storage: 12 Months.